

Is Now Part of

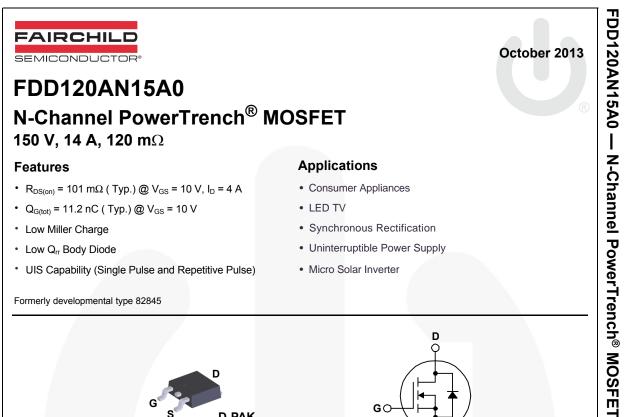


ON Semiconductor®

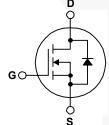
To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese







MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	FDD120AN15A0	Unit	
V _{DSS}	Drain to Source Voltage	150	V	
V _{GS}	Gate to Source Voltage	±20	V	
ID	Drain Current			
	Continuous ($T_C = 25^{\circ}C$, $V_{GS} = 10V$)	14	А	
	Continuous ($T_C = 100^{\circ}C$, $V_{GS} = 10V$)	9.7	А	
	Continuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$) with $R_{\theta JA} = 52^{\circ}C/W$	2.8	А	
	Pulsed	Figure 4	А	
E _{AS}	Single Pulse Avalanche Energy (Note 1)	122	mJ	
P _D	Power dissipation	65	W	
	Derate above 25°C	0.43	W/°C	
T _J , T _{STG}	Operating and Storage Temperature	-55 to 175	°C	

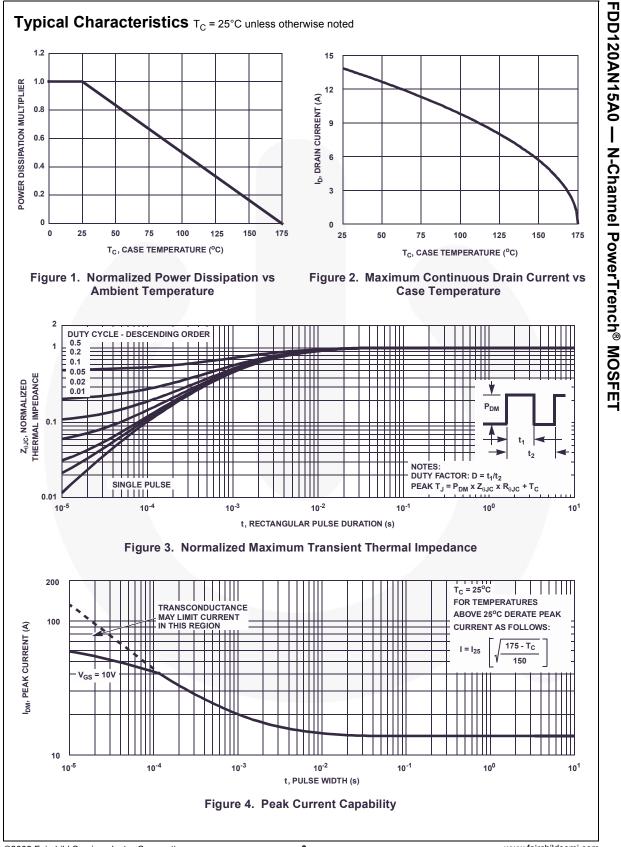
Thermal Characteristics

$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	2.31	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, 1in ² copper pad area, Max.	52	°C/W

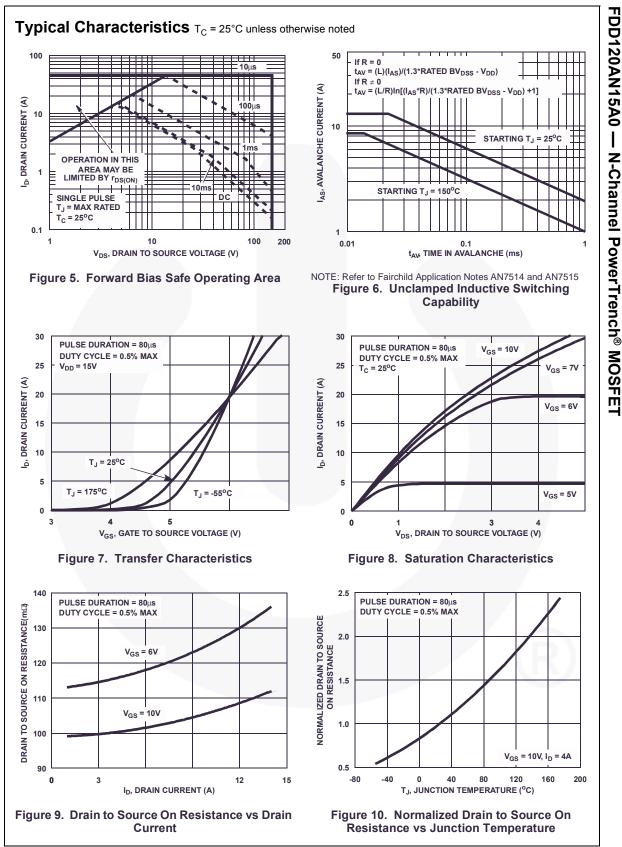
1

Device MarkingDeviceFDD120AN15A0FDD120AN15A0		Package	Reel Size	Tape \	Vidth	Quar	ntity		
		FDD120AN15A0	D-PAK	330 mm	16 mm		2500 units		
Electri	cal Chara	acteristics T _C = 25°C	unless otherwis	se noted					
Symbol	I	Parameter	Test	Conditions	Min	Тур	Мах	Unit	
Off Char	racteristics	s			•			•	
		ource Breakdown Voltage	I _D = 250μA,	$V_{ab} = 0 V_{ab}$	150	-	-	V	
B _{VDSS}	Diamito S	ource breakdown vollage	$V_{DS} = 120V$		-	-	1	V	
I _{DSS}	Zero Gate	Voltage Drain Current	$V_{\rm DS} = 120V$ $V_{\rm GS} = 0V$	T _C = 150 ^o C	-	_	250	μA	
I _{GSS}	Gate to So	ource Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
			65		l	1			
On Char	racteristics	6							
V _{GS(TH)}	Gate to So	ource Threshold Voltage	$V_{GS} = V_{DS},$		2	-	4	V	
			$I_D = 4A, V_{GS}$		-	0.101	0.120		
r _{DS(ON)}	Drain to S	ource On Resistance	$I_D = 2A, V_{GS}$		-	0.113	0.170	Ω	
D3(ON)			I _D = 4A, V _{GS} T _J = 175°C	, = 10V,	-	0.235	0.282		
						1			
-	c Characte								
CISS	Input Capa		V _{DS} = 25V, V	$v_{00} = 0 V$	-	770	-	pF	
C _{OSS}	Output Ca		f = 1MHz	•GS = •••,	-	85	-	pF	
C _{RSS}		ransfer Capacitance			-	17	-	pF	
Q _{g(TOT)}		Charge at 10V	$V_{GS} = 0V$ to			11.2	14.5	nC	
Q _{g(TH)}		Gate Charge	$V_{GS} = 0V$ to	2V V _{DD} = 75V	-	1.4	1.8	nC	
Q _{gs}		ource Gate Charge		$I_D = 4A$	-	3.5	-	nC	
Q _{gs2}		rge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	2.1	-	nC	
Q _{gd}	Gate to Dr	rain "Miller" Charge			-	2.6	-	nC	
Switchir	ng Charact	teristics (V _{GS} = 10V)							
t _{ON}	Turn-On T		1		-	-	33	ns	
t _{d(ON)}	Turn-On D	elay Time			-	6	-	ns	
t _r	Rise Time		V _{DD} = 75V, I	D = 4A	-	16	-	ns	
t _{d(OFF)}	Turn-Off D	elay Time	$V_{GS} = 10V,$		-	30	-	ns	
t _f	Fall Time				-	19	-	ns	
t _{OFF}	Turn-Off T	ïme			-	- /	74	ns	
	ource Diod	le Characteristics	I		•				
			$I_{SD} = 4A$		- /	-	1.25	V	
V _{SD}	Source to	Drain Diode Voltage	$I_{SD} = 2A$		-	-	1.0	V	
	Reverse R	Recovery Time	$I_{SD} = 4A, dI_{SD}/dt = 100A/\mu s$		-	-	61	ns	
t _{rr}		Recovered Charge	$I_{SD} = 4A, dI_{SD}/dt = 100A/\mu s$		-	-	109	nC	

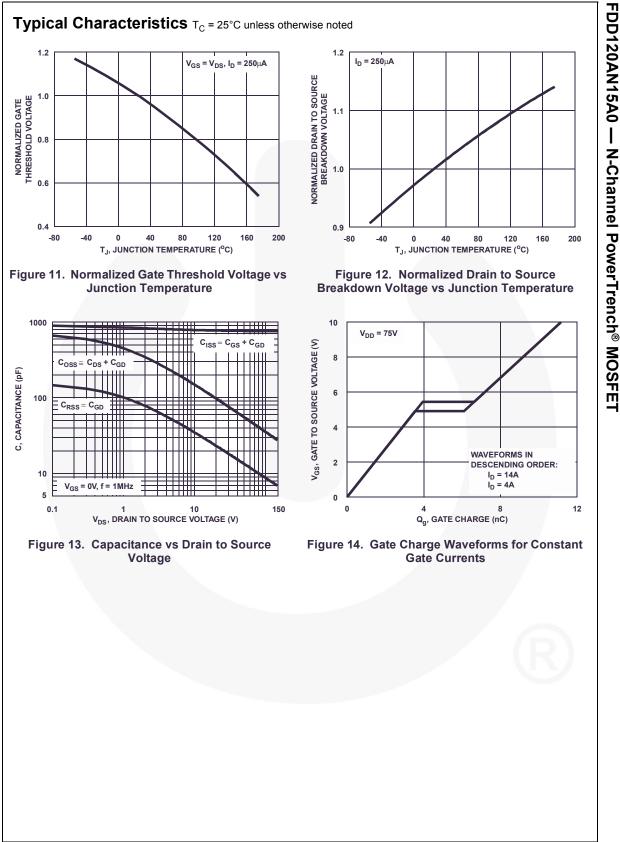
FDD120AN15A0 — N-Channel PowerTrench® MOSFET

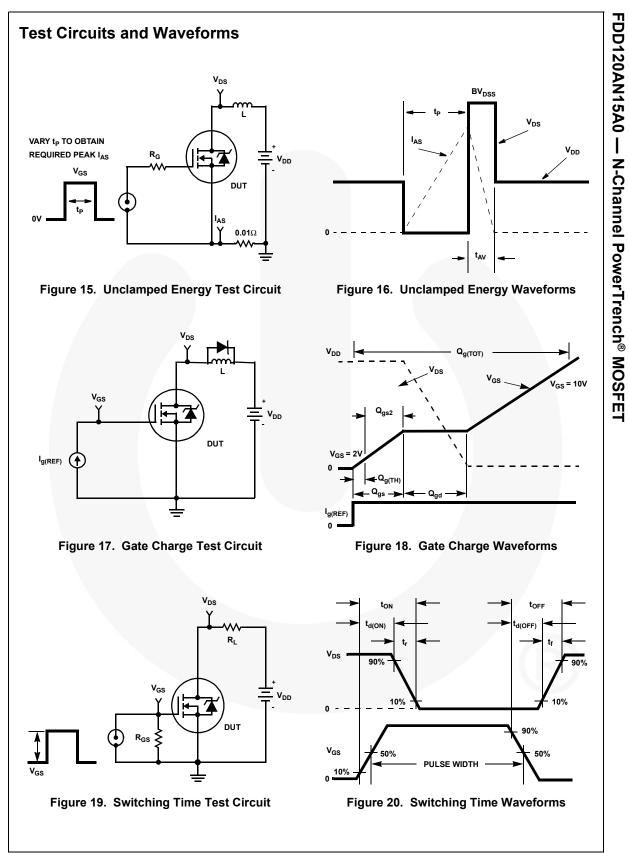


©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2



©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2





©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2

Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, $T_A~(^oC)$, and thermal resistance $R_{\theta JA}~(^oC/W)$ must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 1oz copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

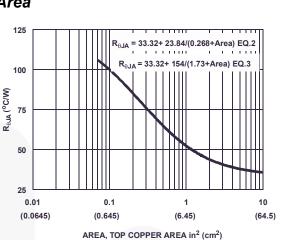
$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
 (EQ. 2)

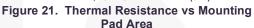
Area in Inches Squared

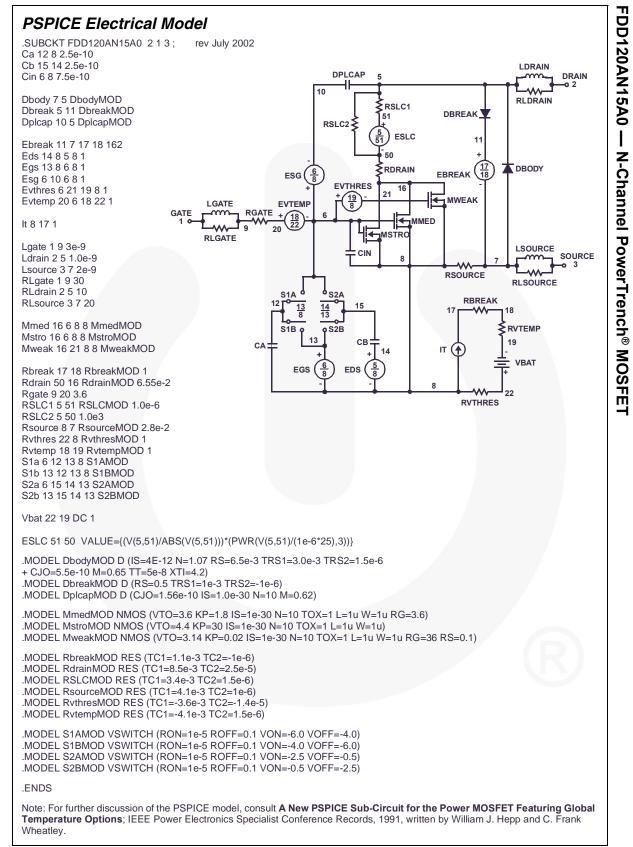
$$R_{\theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
(EQ. 3)

Area in Centimeters Squared

©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2

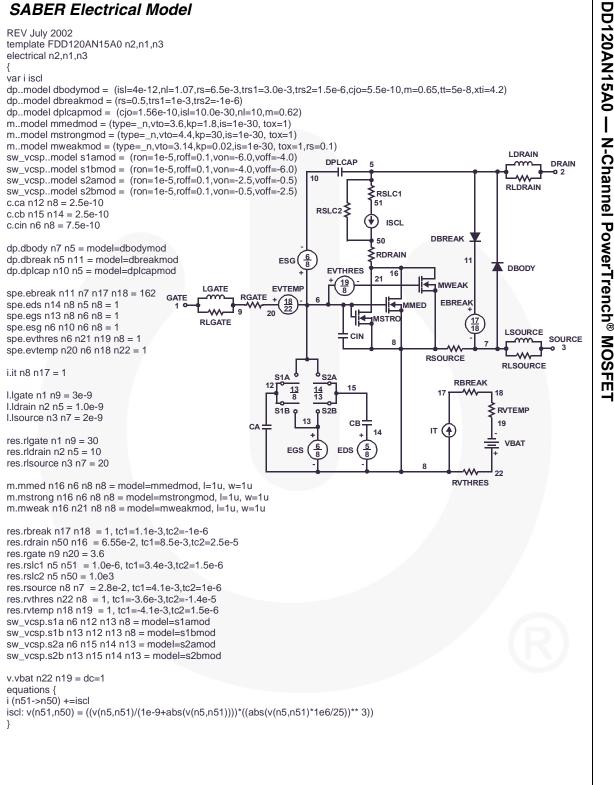




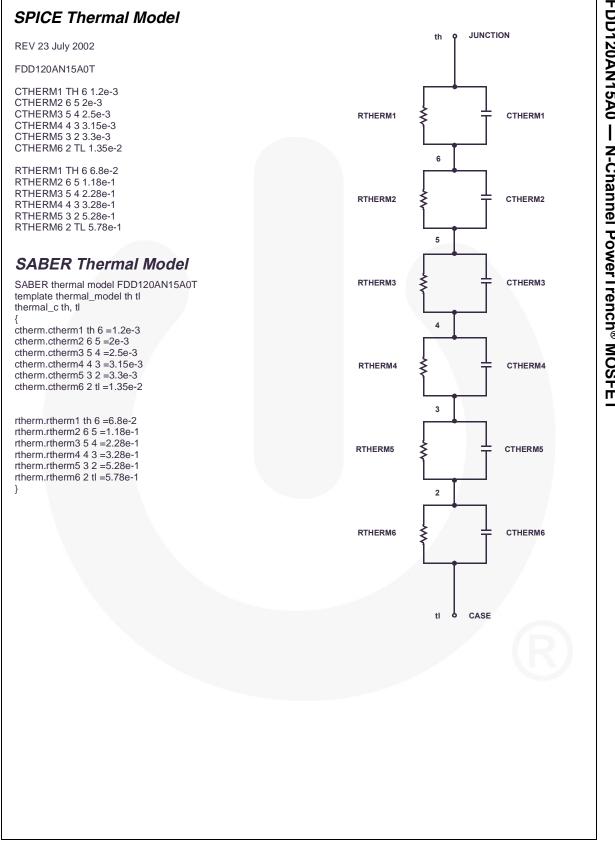


©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2

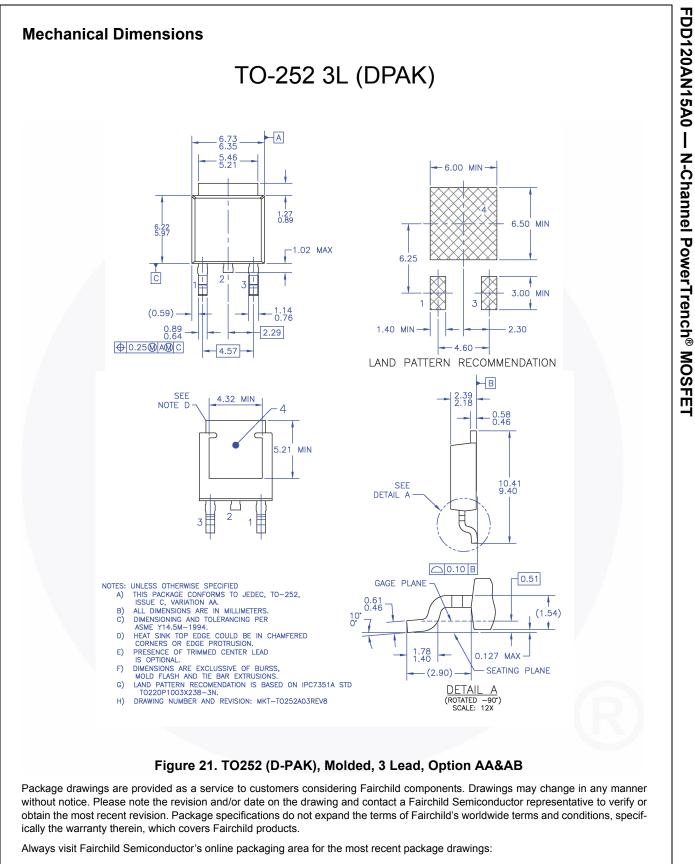
SABER Electrical Model



©2002 Fairchild Semiconductor Corporation FDD120AN15A0 Rev. C2



FDD120AN15A0 — N-Channel PowerTrench[®] MOSFET



http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT252-003

Dimension in Millimeters



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™
AX-CAP [®] *
BitSiC™
Build it Now™
CorePLUS™
CorePOWER™
CROSSVOLT™
CTL™
Current Transfer Logic™
DEUXPEED®
Dual Cool™_
EcoSPARK [®]
EfficentMax™
ESBC™

airchild Fairchild Semiconductor® FACT Quiet Series™ FACT® FAST® FastvCore™ FETBench™ FPS™

FRFET® Global Power ResourceSM GreenBridge™ Green FPS™ Green FPS™ e-Series™ G*max*™ GTO™ IntelliMAX[™] ISOPLANAR™ Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver® OptoHiT™ **OPTOLOGIC[®] OPTOPLANAR[®]**

F-PFS™

()_® PowerTrench® PowerXS™ Programmable Active Droop™ QFET QS™ Quiet Series™ RapidConfigure[™] Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM® STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS®

GENERAL ®* TinyBoost TinyBuck® TinyCalc™ TinyLogic® TINYOPTO™ TinvPower™ TinyPWM™ TinyWire™ TranSiC™ TriFault Detect™ TRUECURRENT®* uSerDes™ UHC® Ultra FRFET™ UniFFT™ VCX[™] VisualMax™ VoltagePlus™

Sync-Lock™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

SvncFET™

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

XS™

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS **Definition of Terms**

FDD120AN15A0 Rev. C2

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
		Rev

©2002 Fairchild Semiconductor Corporation

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi: FDD120AN15A0